

SECO-HVDCDC1362-40W15V-GEVB



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40 W SiC High-Voltage Auxiliary Power Supply for HEV & BEV Applications Evaluation Board User's Manual

EVAL BOARD USER'S MANUAL

Introduction

SECO-HVDCDC1362-40W15V-GEVB is highly efficient and primary-side regulated (PSR) auxiliary power supply targeting HEV and EV automotive power trains. The design provides a stable 15 V output and 40 W over a wide input DC voltage range from 250 V to 900 V, and is therefore suitable for 400 V and 800 V battery systems.

The board employs the NCV1362 quasi-resonant peak current PSR flyback controller, the 3-lead cost-optimized NVHL160N120SC1 160 mΩ 1200 V silicon carbide (SiC) MOSFET, and the FFSP0665B-F085 SiC diode.

Thanks to the high blocking voltage capabilities and ultra-low gate charge (34 nC) value of the SiC FET, the switching losses are significantly reduced, and the board exhibits a superior efficiency for the application up to 86% in low line input conditions. The notable driving capabilities of the NCV1362 controller allows for direct operation of the SiC FET at 12 V without a pre-driver, simplifying the layout and cutting down the component count.

The flyback transformer provides 4 kV isolation and is optimized to minimize the losses on the RCD snubber. Consequently the system effectively dampens the drain voltage overshoot at high line, and provides 100 V margin for the SiC FET. The board is fully realized with automotive qualified semiconductors and passive devices. Industrial grade replacements are also available.

Features

- NCV1362 (Automotive) / NCP1362 (Industrial) Quasi-resonant Peak Current PSR Flyback Controller
- Fully Automotive Qualified Devices
- $V_{in} = 240\text{ V} - 900\text{ V DC}$ Only
- $V_{out} = 15\text{ V} / 40\text{ W}$ Continuous
- Electromagnetic Compatibility (EN 55015 Limits)
- High Efficiency up to 85.5%
- SiC FET Directly Operated at 12 V by the IC
- Excellent Thermal Performance

Applications

- HEV & EV Vehicles Auxiliary Power Supplies
- Automotive Powertrain Systems
- EV Charging and DC-DC Conversion
- Industrial DC-DC Conversion, Solar Inverts (with Industrial grade)



(Top View)



(Bottom View)

Figure 1. Board Layout

Benefits

- Superior Efficiency with SiC Devices
- Stable Performance across a Wide Input Voltage Range (250 Vdc – 900 Vdc)
- Reduced Bill-of-Material and Cost-optimized
- Fully AEC-Q Qualified Parts
- EMC within EN 55015 Limits
- Single Layer PCB

Collateral

- [NVHL160N120SC1](#)
- [NCV1362](#)
- [SECO-HVDCDC1362-40W15V-GEVB](#)
- [References](#)

SECO-HVDCDC1362-40W15V-GEVB

Scope and Purpose

The purpose of this user's manual is to present the design of an auxiliary power supply with automotive qualified parts NCV1362 (NCP1362) and NVHL160N120SC1 SiC FET. The design was tested as described in this document but not

qualified regarding safety requirements or manufacturing and operation over the complete operating temperature range or lifetime. The hardware is intended for testing under laboratory conditions and by trained specialists only.

System Overview

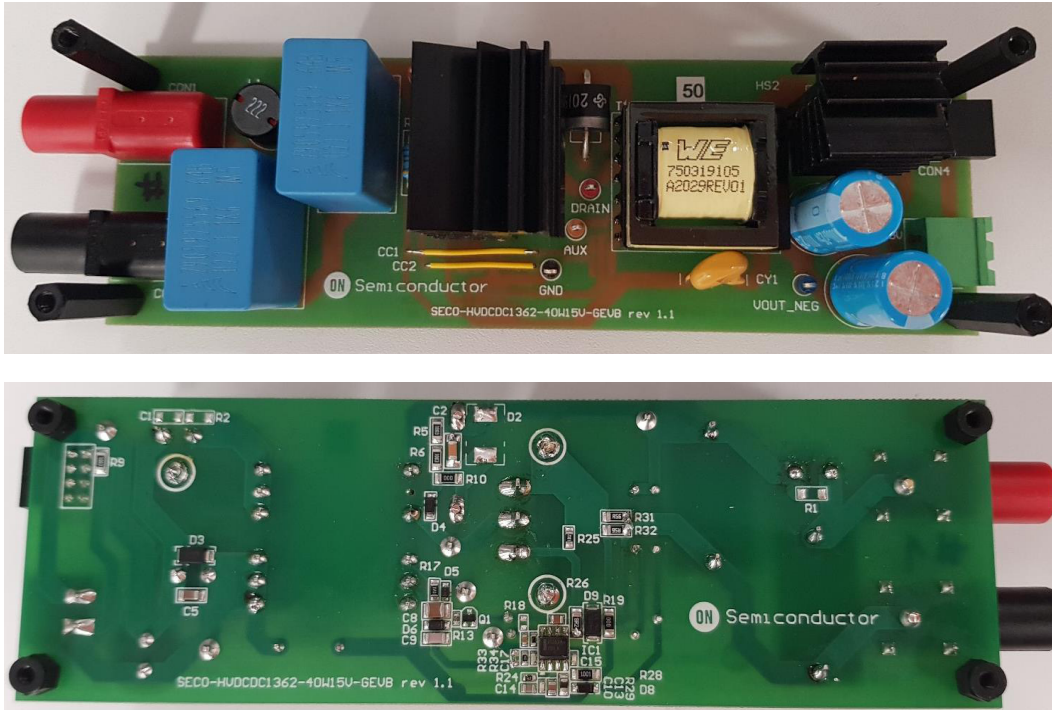


Figure 2. Evaluation Board Photo

Block Diagram

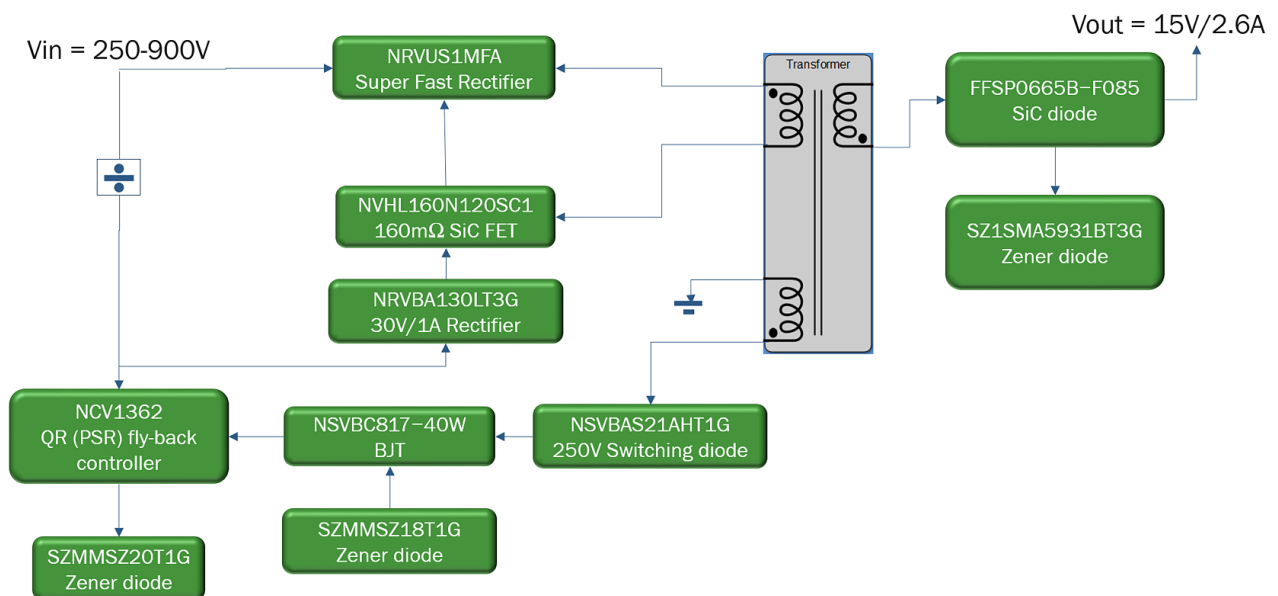


Figure 3. Block Diagram

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SPECIFICATION

Parameters	Values
Input	
Voltage	250–900 VDC
Current	191 mA ($V_{in} = 250\text{ V}$), 56 mA ($V_{in} = 900\text{ V}$)
Output	
Power	40 W
Voltage	15 VDC
Current per branch	2.66 A
Total current	2.66 A
Efficiency at full load	85.5% ($V_{in} = 250\text{ V}$)
Temperature at full load	98°C ($V_{in} = 6\text{ V}$), 74.5°C ($V_{in} = 15\text{ V}$), 76°C ($V_{in} = 18\text{ V}$)
Control	
Core part	NCV1362
Topology	Flyback
Switching frequency	50 kHz
Operation mode	DCM
Primary side peak current	1.5 A
Construction	
Board size	52.2 x 164.2 x 40 mm
Transformer	
Dielectric insulation	4000 VAC, 1 min.
Inductance	0.95 mH \pm 10%
Leakage inductance	20 μ H typ. / 40 μ H max.
Safety standard	IEC62368-1
Pollution degree	1
Application	
HEV & EV vehicles, automotive powertrain systems, EV charging and DC–DC conversion	

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Schematic

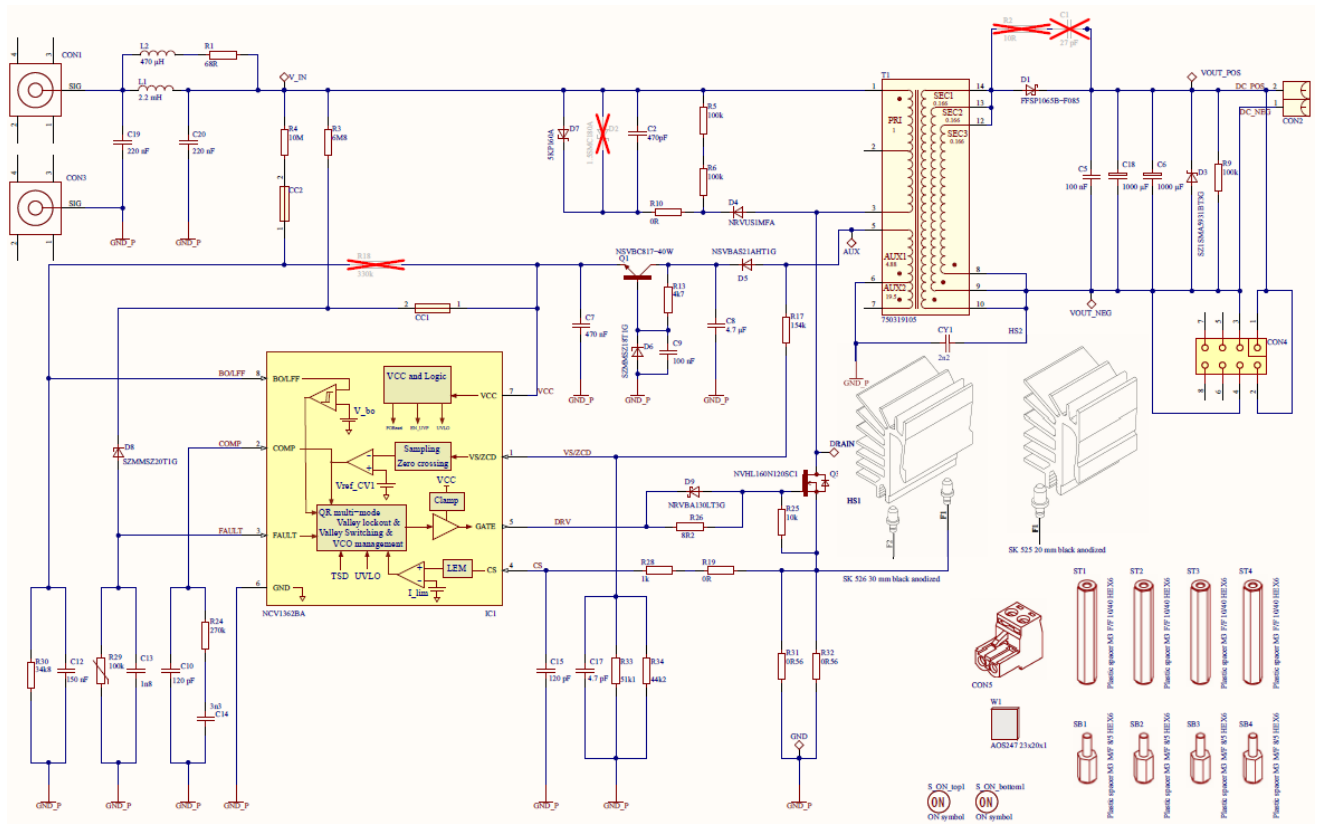


Figure 4. Evaluation Board Schematic

TEST REPORT

This section presents the results of the tests conducted on the power supply.

- Efficiency DC/DC at input voltage range and full load
- Waveforms at 240 V, 500 V, 900 V at full load / open circuit
- Load transients 15%–85% and 15%–85% load
- Thermal camera view
- Electromagnetic compatibility

Efficiency DC/DC at Input Voltage Range and Full Load

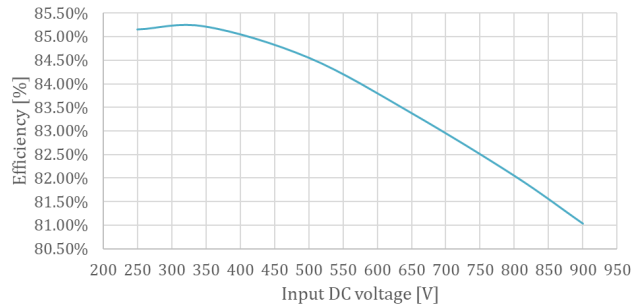
Measured conditions:

- Output power $P_{out} \sim 40\text{ W}$
- Electronic load: Chroma 6147A used channel 3 as CRH (constant resistance high mode $5.5\ \Omega \rightarrow 2.66\ \text{A}$)

List of equipment:

- DC source: Magna-Power 0–1000V
- Power analyzer: Textronix PA3000
- Electronic load: Chroma

Efficiency 40W HV Auxiliary



Power losses 40W HV Auxiliary

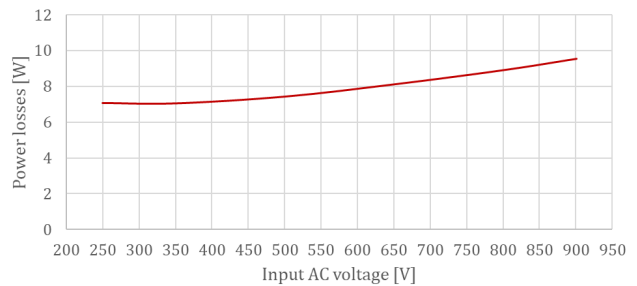


Figure 5.

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Waveforms at 240 V, 500 V, 900 V at Full Load / Open Circuit

Measured conditions:

- Output power $P_{out} \sim 40\text{ W}$
- Electronic load: Chroma 6147A used channel 3 as CRH (constant resistance high mode $5.5\ \Omega \rightarrow 2.66\ \text{A}$)

List of equipment:

- DC source: Magna-Power 0-1000V
- Power analyzer: Textronix PA3000
- Electronic load: Chroma
- Oscilloscope: Lecroy HDO8038

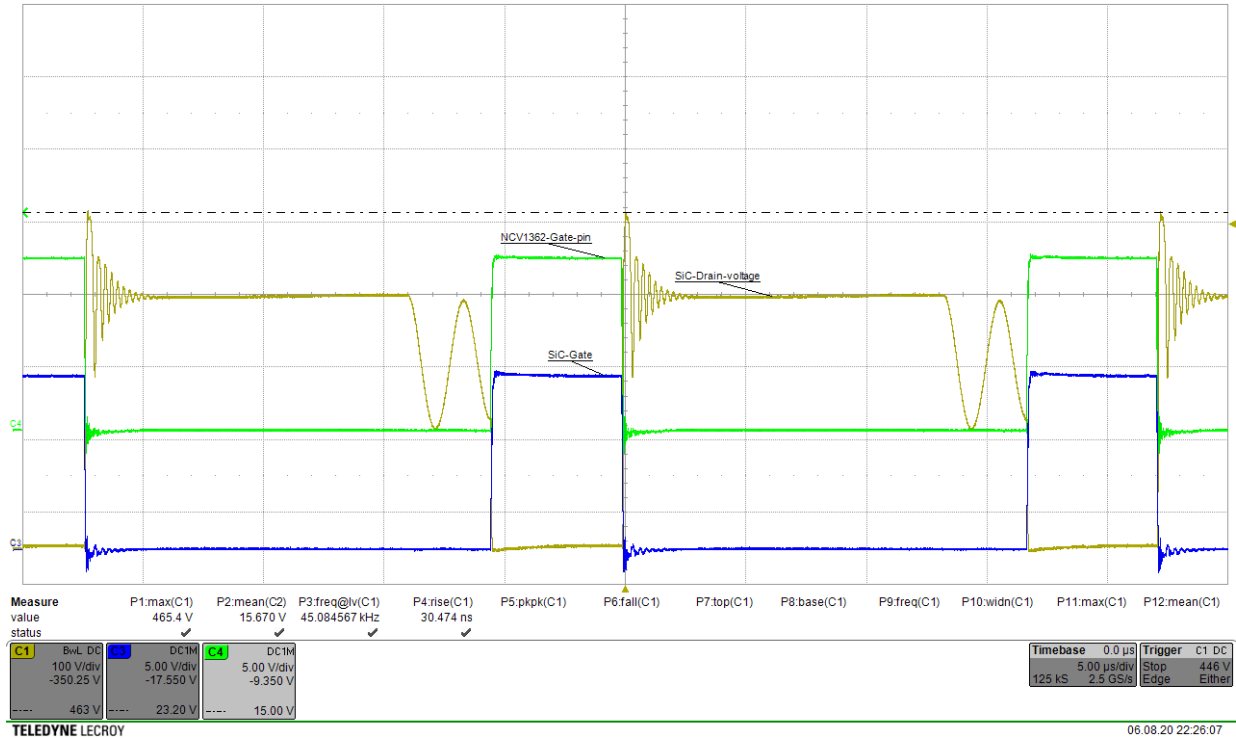


Figure 6. 250 V DC Full Load

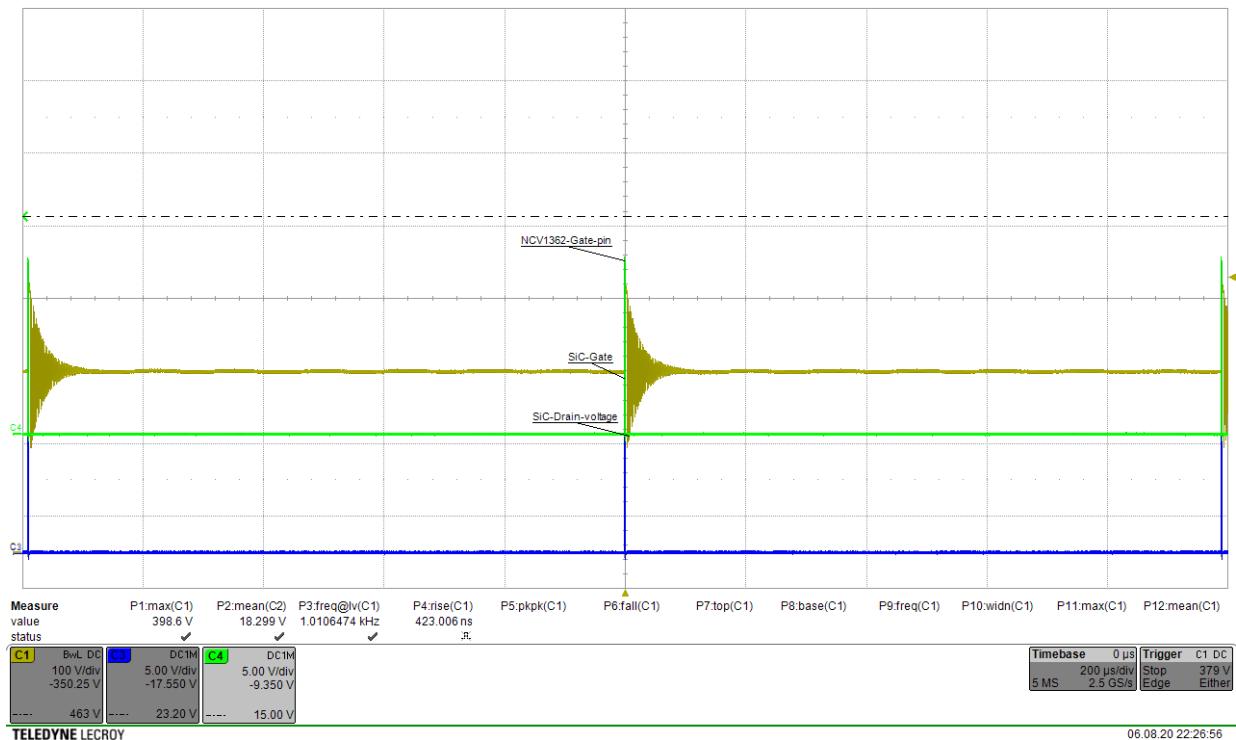


Figure 7. 250 V DC Open Circuit

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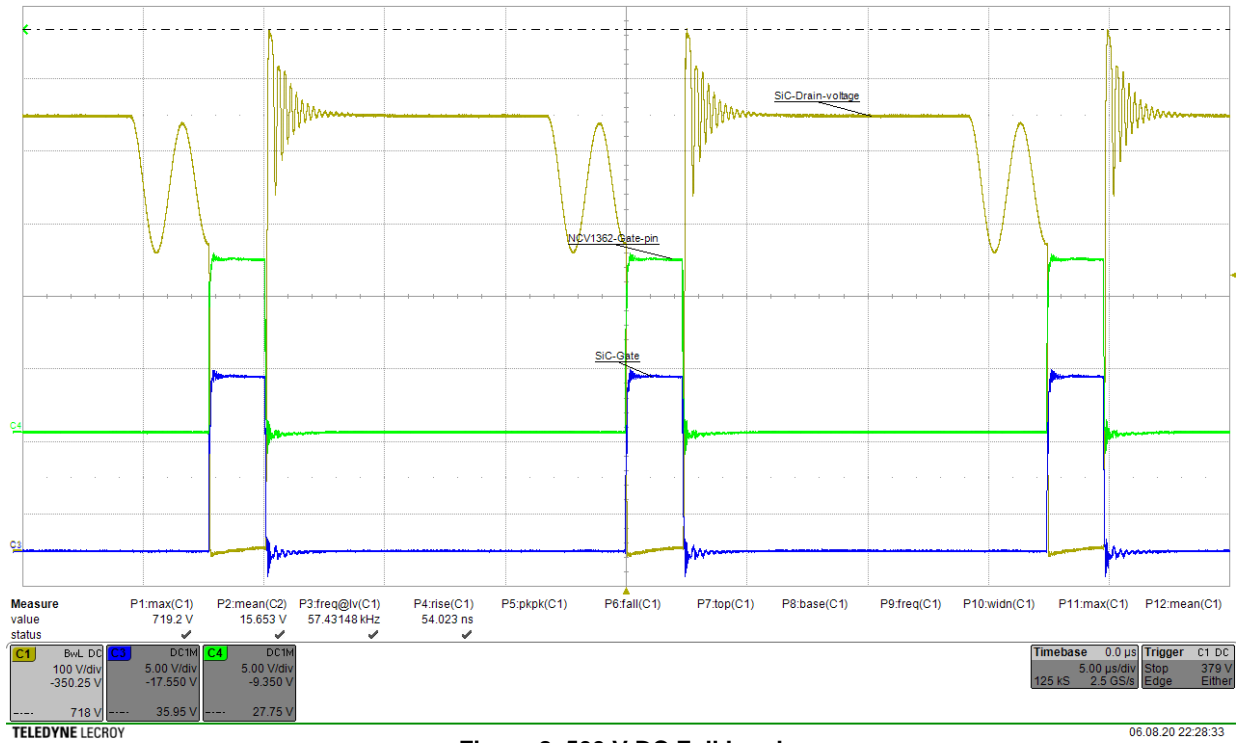


Figure 8. 500 V DC Full Load

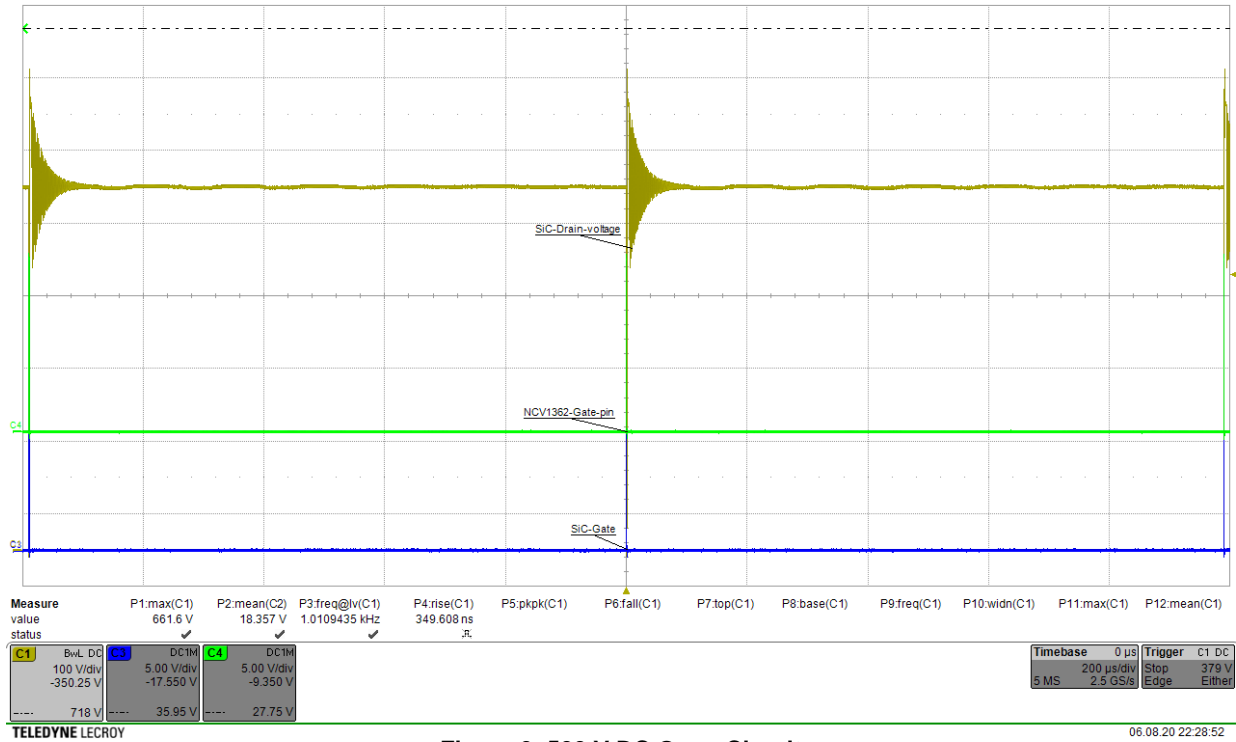


Figure 9. 500 V DC Open Circuit

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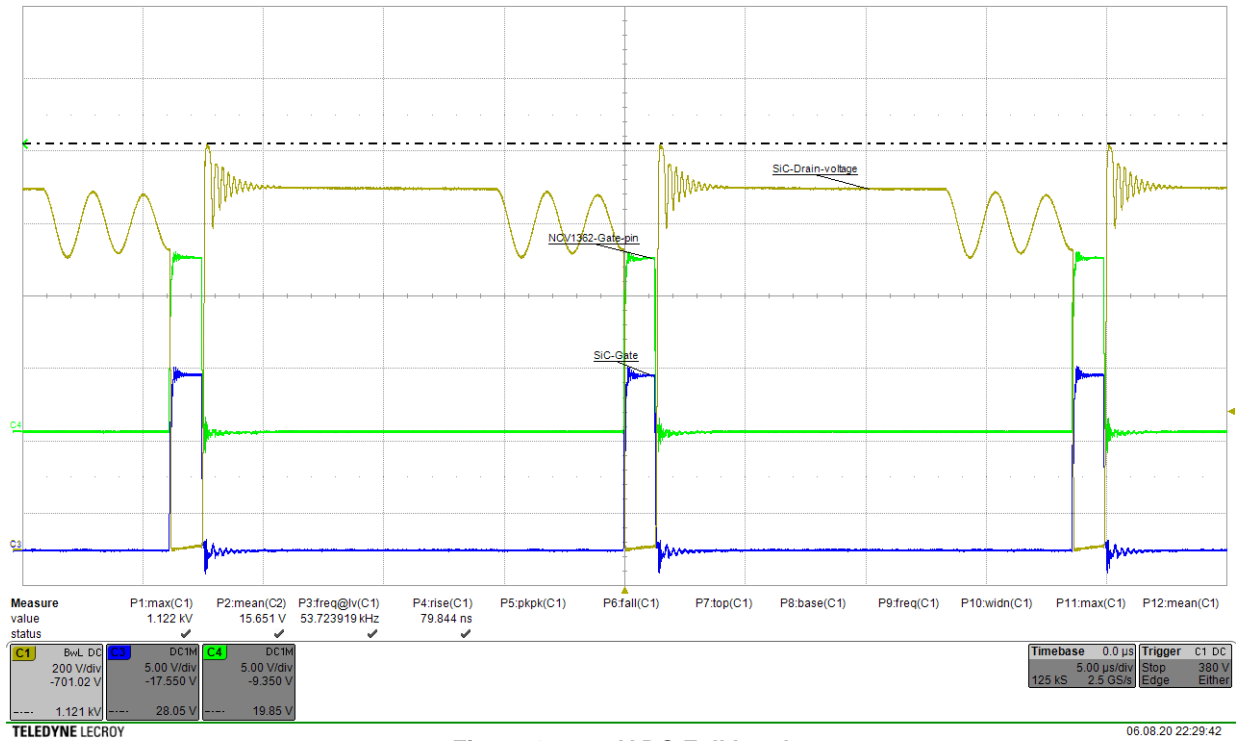


Figure 10. 900 V DC Full Load

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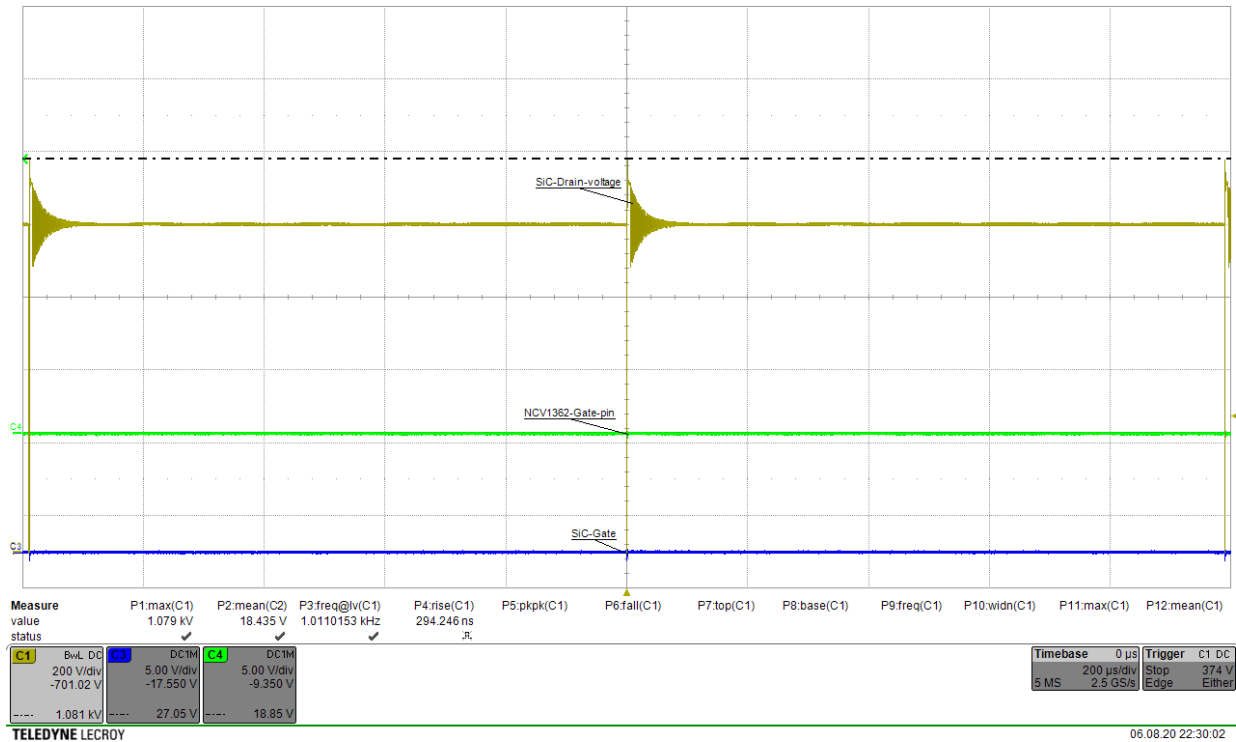


Figure 11. 900 V DC Open Circuit

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Load Transients 15%–85% and 15%–85% Load

Measured conditions:

- Output power $P_{out} \sim 40\text{ W}$
- Electronic load: Chroma 6147A used channel 3 as CCDH (constant current dynamic mode 0.39 A \rightarrow 2.26 A)

List of equipment:

- DC source: Magna-Power 0–1000V
- Power analyzer: Textronix PA3000
- Electronic load: Chroma
- Oscilloscope: Lecroy HDO8038

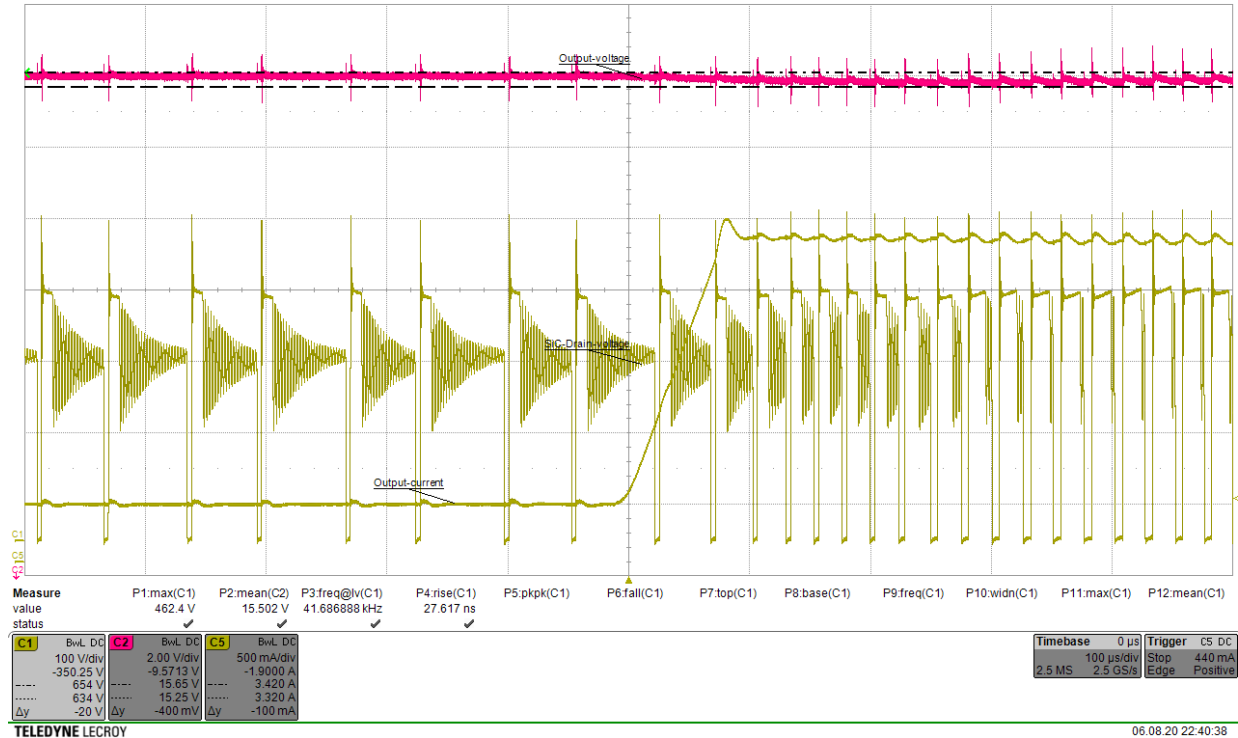


Figure 12. 250 V – 15% to 85%

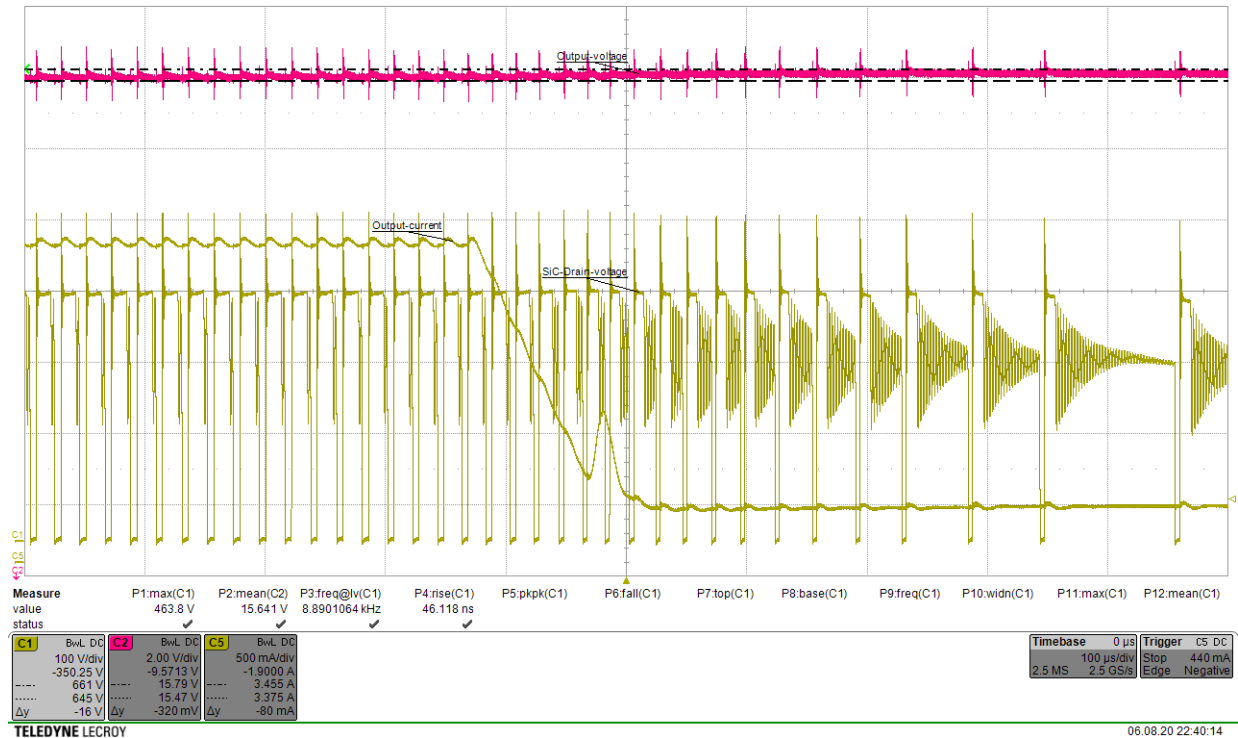


Figure 13. 250 V – 85% to 15%

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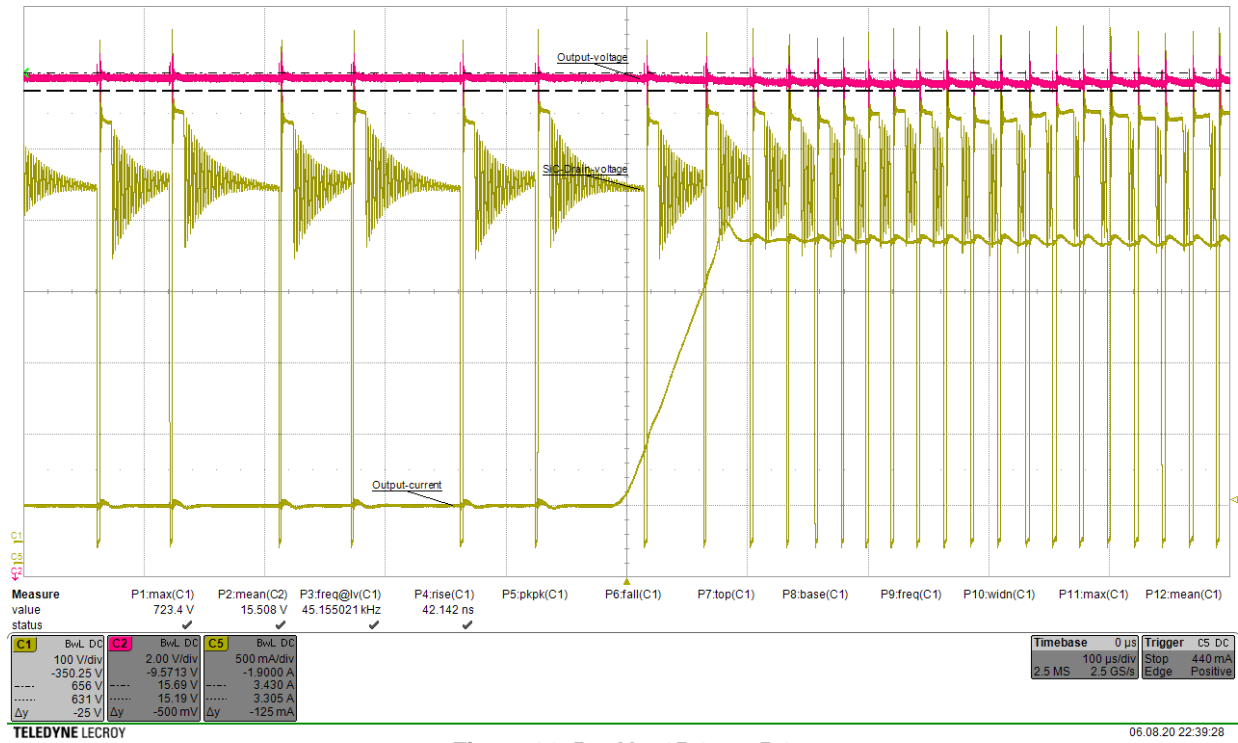


Figure 14. 500 V – 15% to 85%

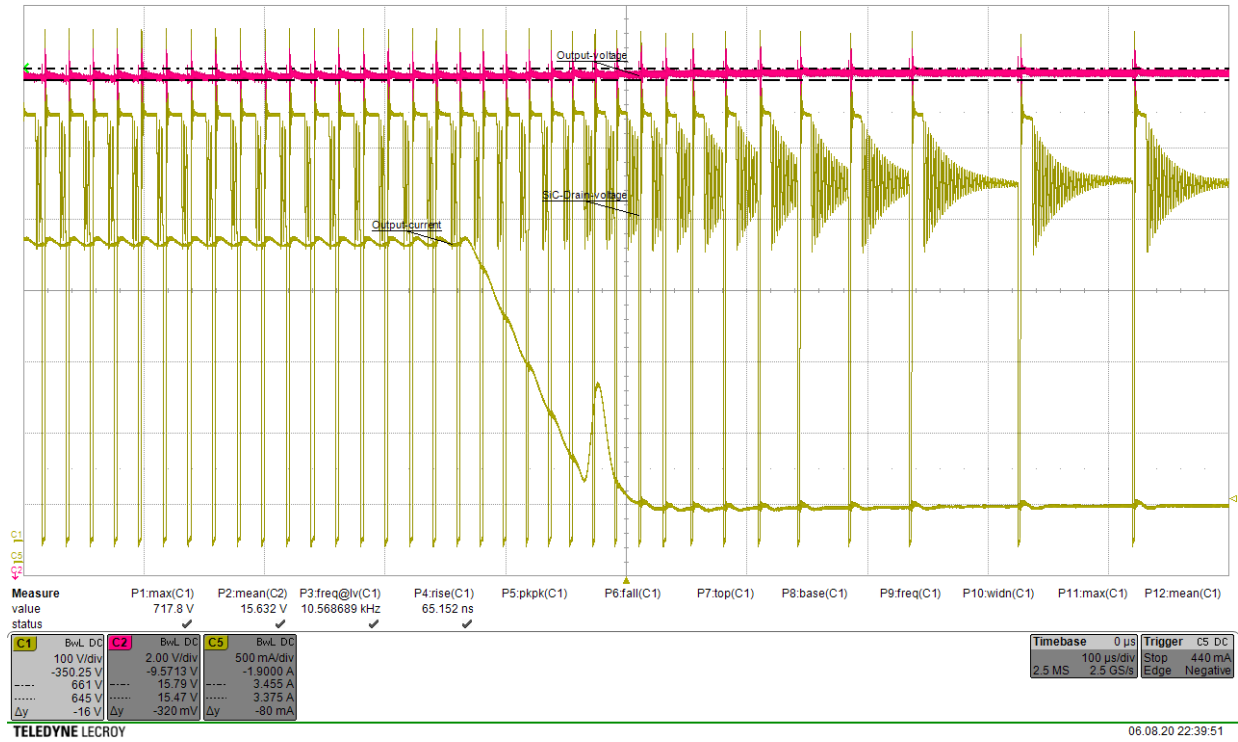


Figure 15. 500 V – 85% to 15%

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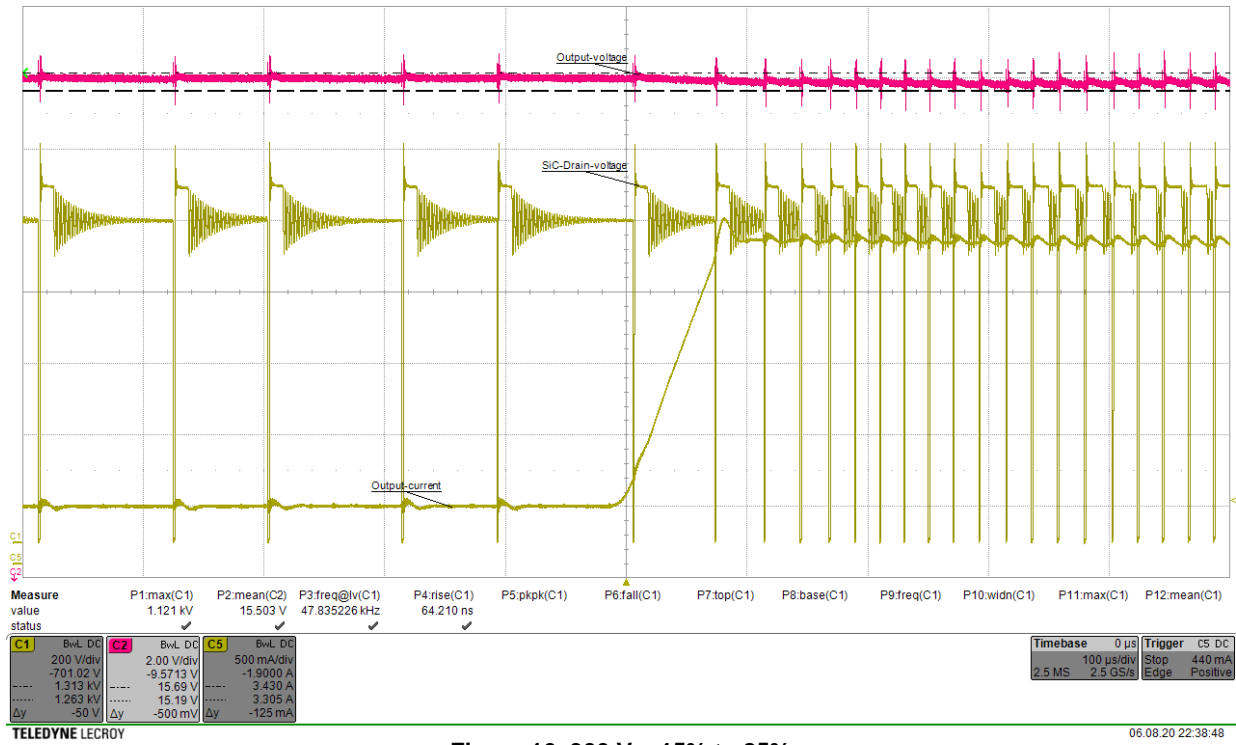


Figure 16. 900 V – 15% to 85%

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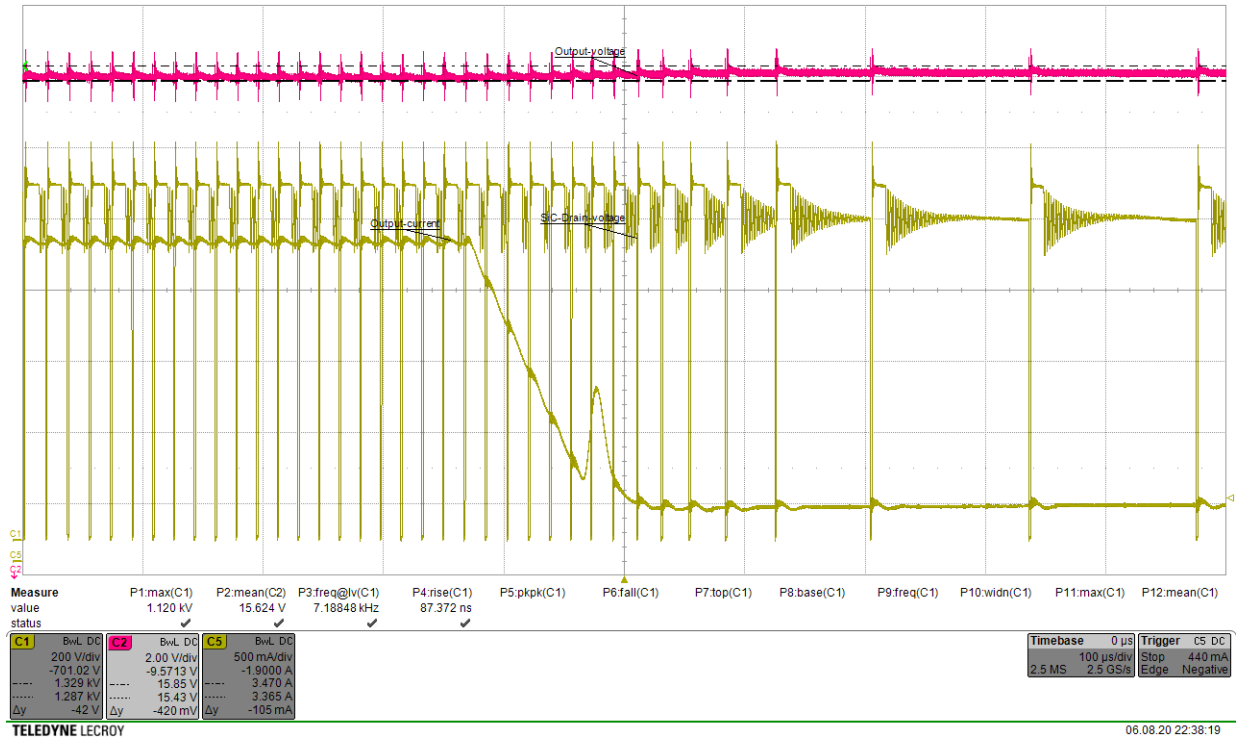


Figure 17. 900 V – 85% to 15%

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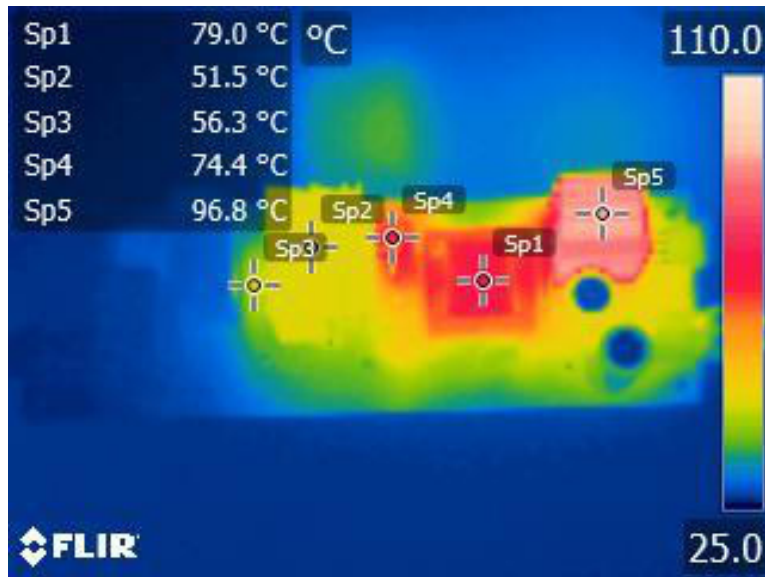
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Thermal Camera View

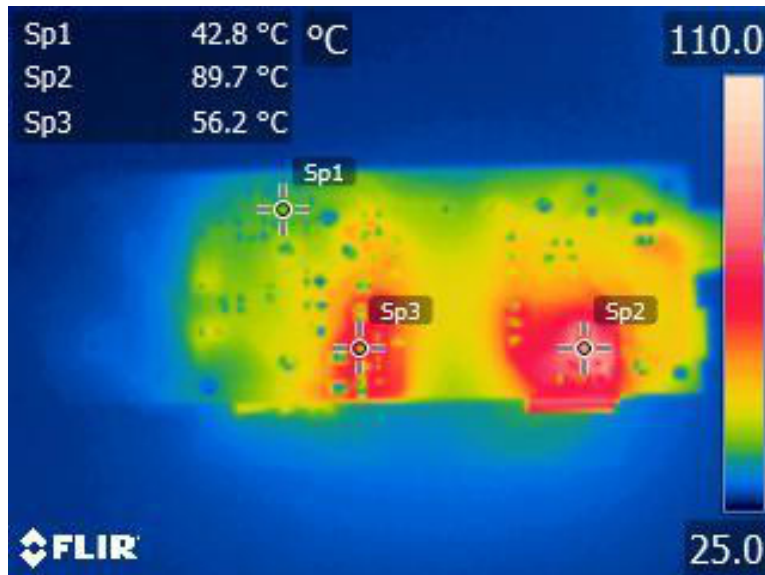
Measured conditions:

- Output power $P_{out} \sim 40\text{ W}$
- Electronic load: Chroma 6147A used channel 3 as CRH (constant resistance high mode $5.5\ \Omega \rightarrow 2.66\text{ A}$)

- Input voltage $\sim 900\text{ V DC}$
- After 5 minutes in this conditions



- Sp1 – Transformer
- Sp2 – SiC switcher heatsink
- Sp3 – Startup high voltage resistor
- Sp4 – Axial TVS diode
- Sp5 – Secondary rectifier heatsink



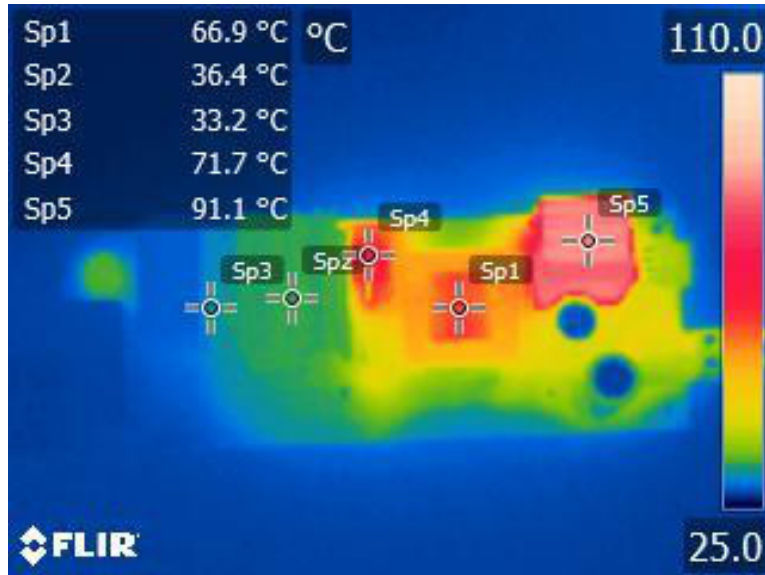
- Sp1 – IC NCV 1362
- Sp2 – Secondary rectifier heatsink bottom
- Sp3 – Axial TVS diode bottom side

Figure 18.

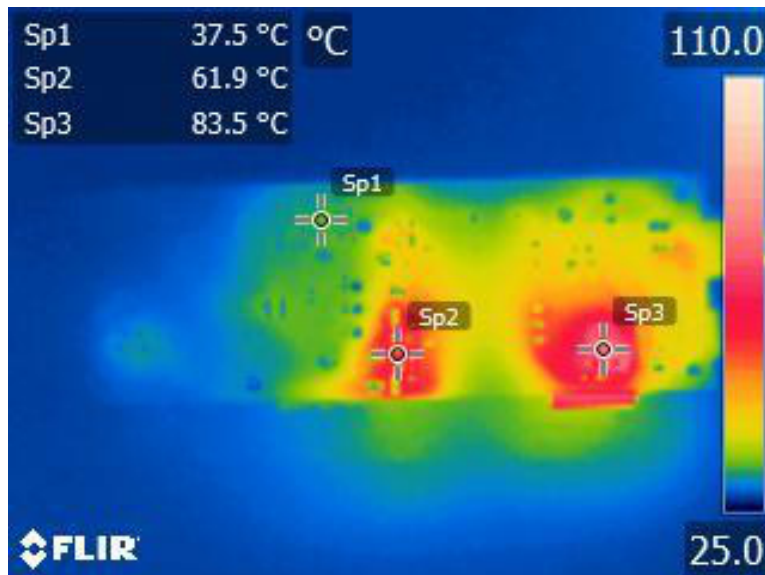
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Measured conditions:

- Output power $P_{out} \sim 40\text{ W}$
- Electronic load: Chroma 6147A used channel 3 as CRH (constant resistance high mode $5.5\ \Omega \rightarrow 2.66\text{ A}$)
- Input voltage $\sim 250\text{ V DC}$
- After 5 minutes in this conditions



Sp1 – Transformer
 Sp2 – SiC switcher heatsink
 Sp3 – Startup high voltage resistor
 Sp4 – Axial TVS diode
 Sp5 – Secondary rectifier heatsink



Sp1 – IC NCV 1362
 Sp2 – Secondary rectifier heatsink bottom
 Sp3 – Axial TVS diode bottom side

Figure 19.

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Electromagnetic Compatibility – Conducted Emissions EN55015 Limits

Measured conditions:

- Output power $P_{out} \sim 18 \Omega$ resistive load
- Input voltage $\sim 250 \text{ V}$

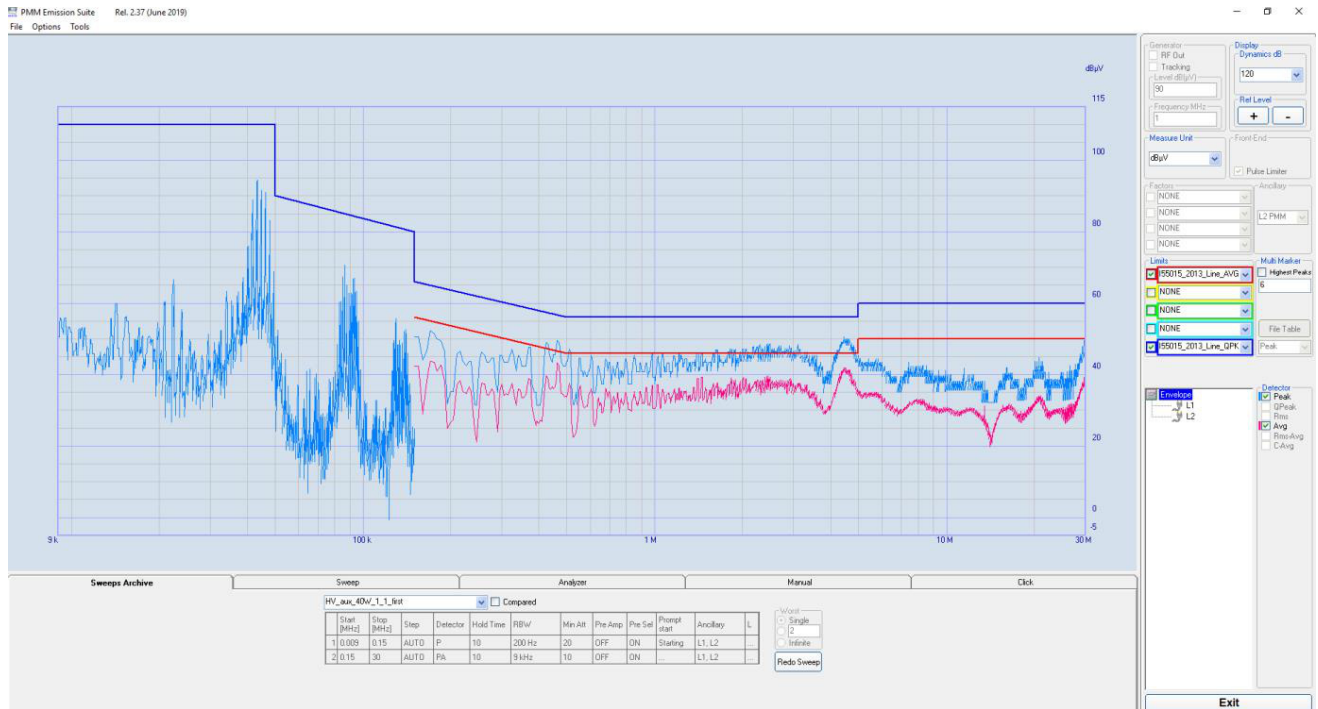


Figure 20.

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Transformer Design

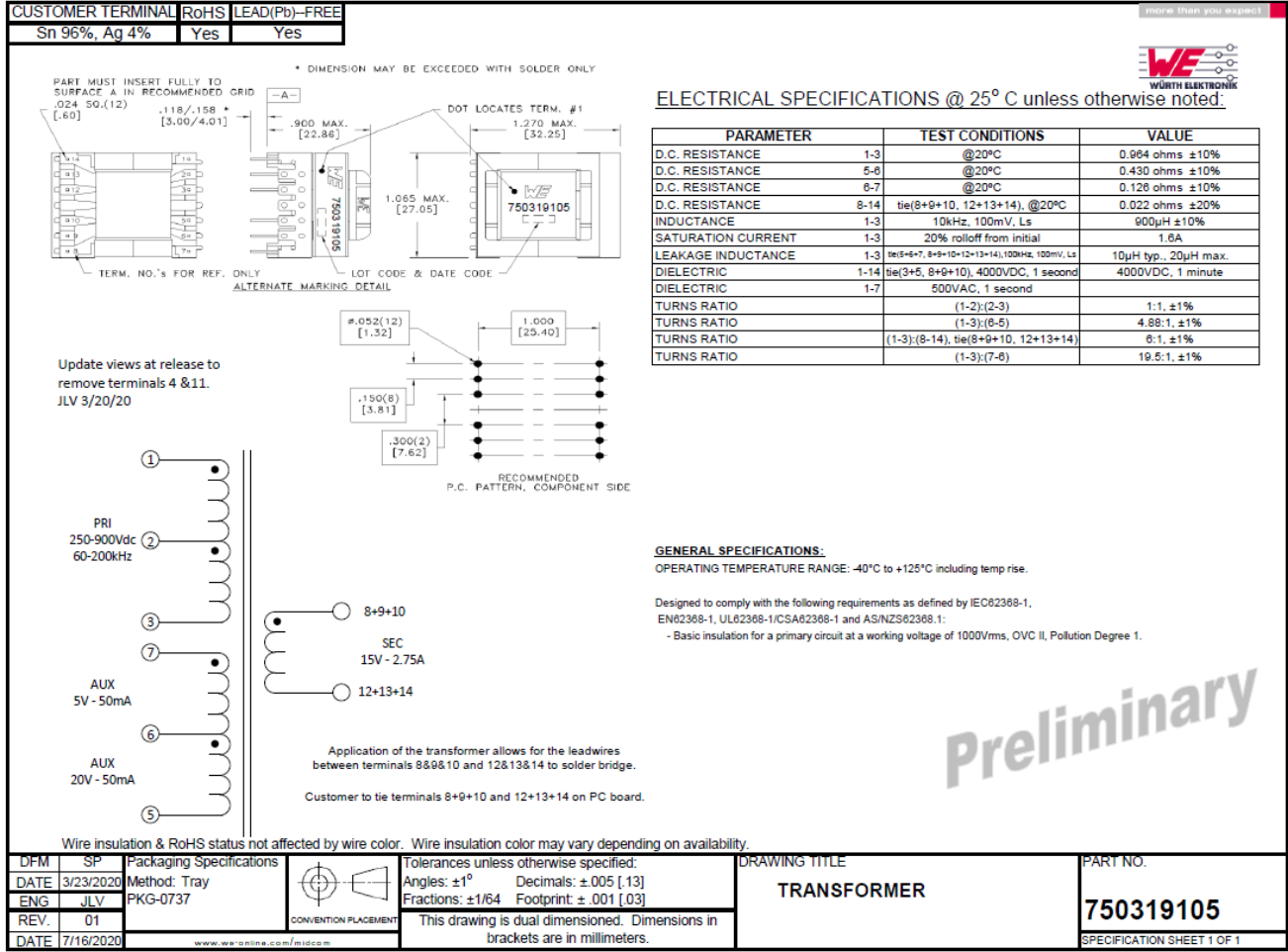


Figure 21. Drawing and Parameters of Used Transformer

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Development Resources and Tools

Collateral, development files and other development resources listed below are available at [SECO-HVDCDC1362-40W15V-GEVB](http://www.onsemi.com/SECO-HVDCDC1362-40W15V-GEVB)

- Schematics
- BOM (below as well)
- Manufacturing files
- PCB layout (below as well)
- Source files
- Simulation model (below as well)

Table 1. BILL OF MATERIALS

#	Designator	Comment	Description
1.	C2	470 pF	MLC capacitor 470pF 1kV ±10% X7R Würth Elektronik
2.	C5	100 nF	Multilayer Ceramic Capacitors MLCC – SMD 1206 25 V 100 nF C0G ± 1 % AEC-Q202 –55 – 125 °C
3.	C6, C18	1000 µF	ALU electrolyte high current ripple 1000 µF 25V 20% Nichicon
4.	C7	470 nF	Multilayer Ceramic Capacitors MLCC – SMD 0805 50 V 470 nF X7R ± 10 % AEC-Q202 –55 – 125 °C
5.	C8	4.7 µF	Multilayer Ceramic Capacitors MLCC – SMD 1210 50 V 4.7 µF X7R ± 10 % AEC-Q202 –55 – 125 °C
6.	C9	100 nF	Multilayer Ceramic Capacitors MLCC – SMD 1206 50 V 100 nF C0G ± 5 % AEC-Q202 –55 – 125 °C
7.	C10, C15	120 pF	Multilayer Ceramic Capacitors MLCC – SMD 0603 100 V 120 pF C0G ± 5 % AEC-Q202 –55 – 125 °C
8.	C12	150 nF	Multilayer Ceramic Capacitors MLCC – SMD 0603 25 V 150 nF X7R ± 10 % AEC-Q202 –55 – 125 °C
9.	C13	1n8	Multilayer Ceramic Capacitors MLCC – SMD 0805 100 V 1n8 C0G ± 5 % AEC-Q202 –55 – 125 °C
10.	C14	3n3	Multilayer Ceramic Capacitors MLCC – SMD 0805 100 V 3n3 C0G ± 5 % AEC-Q202 –55 – 125 °C
11.	C17	4.7 pF	Multilayer Ceramic Capacitors MLCC – SMD 0603 100 V 4.7 pF C0G ± 5 % AEC-Q200 –55 – 125 °C
12.	C19, C20	220 nF	MMKT film capacitor 220n 500Vac/1600Vdc TDK
13.	CON1	RED	Banana Test Connector, 4mm, Receptacle, PCB Mount, 24 A, 1 kV, Gold Plated Contacts, Red
14.	CON2	691 313 510 002	PCB right angle connector 2 pins 5.08 mm pitch Würth Elektronik
15.	CON3	BLACK	Banana Test Connector, 4mm, Receptacle, PCB Mount, 24 A, 1 kV, Gold Plated Contacts, Black
16.	CON4	613 008 243 121	WR-PHD 2.54 mm Angled Dual Socket Header 2x4 pins
17.	CON5	691 351 500 002	Cable connector series 351 2pins 5.08 mm Würth Elektronik
18.	CY1	2n2	Disc ceramic capacitor 2n2 1500 VDC Y5U 10 % Vishay AEC-Q200
19.	D1	FFSP1065B-F085	Ultra fast Schottky SiC diode 650V 10A AEC-Q101 ON Semiconductor
20.	D3	SZ1SMA5931BT3G	TVS zener diode 18 V 83 mA SMA AEC-Q101 ON Semiconductor
21.	D4	NRVUS1MFA	Super Fast diode 1000 V 1 A 75 ns SOD123FA AEC-Q101, ON Semiconductor
22.	D5	NSVBAS21AHT1G	Switching diode 250V 200mA SOD323 AEC-Q101 ON Semiconductor
23.	D6	SZMMSZ18T1G	Zener Single Diode, 18 V, 500 mW, SOD-123, 5 %, 2 Pins, 150 °C, AEC-Q101
24.	D7	5KP160A	TVS 160V 5000W True hole unidirectional VISHAY AEC-Q101
25.	D8	SZMMSZ20T1G	Zener Diodes 20V 500mW SOD123 AEC-Q101 ON Semiconductor
26.	D9	NRVBA130LT3G	Schottky diode 30 V 1 A SMA ON Semiconductor
27.	HS1	SK 526 30 mm black anodized	Heatsink Fischer Elektronik SK 526 30 mm black anodized
28.	HS2	SK 525 20 mm black anodized	Heatsink Fischer Elektronik SK 525 20 mm black anodized
29.	IC1	NCV1362BA	Automotive Primary Side Flyback Controller
30.	L1	2.2 mH	Fixed Inductors RFB 1010 Lead Rad 2.2 mH 0.41A 4.1 Ω

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Table 1. BILL OF MATERIALS (continued)

#	Designator	Comment	Description
31.	L2	470 μ H	Fixed Inductors RFB 1010 Lead Rad 470 μ H 0.9A 0.81 Ω
32.	Q1	NSVBC817-40W	General purpose NPN transistor 45V 500mA ON Semiconductor
33.	Q3	NVHL160N120SC1	SiC NMOS 1200V 17A 160 m Ω ON Semiconductor
34.	R1	68R	SMD thick film resistor 68R 1206 1% 660 mW Panasonic
35.	R3	6M8	High Ohmic / High Voltage Metal Glaze Leaded Resistors 0207 6M8 5% 250 mW Vishay
36.	R4	10M	High Ohmic / High Voltage Metal Glaze Leaded Resistors 0207 10M 5% 250 mW Vishay
37.	R5, R6, R9	100k	SMD Chip Resistor, 100 k Ω , MCWR Series, 200 V, Thick Film, 1206 [3216 Metric], 250 mW Multicomp
38.	R10, R19	0R	SMD Chip Resistor, 0 Ω , ERJ8G Series, 200 V, Thick Film, 1206 [3216 Metric], 250 mW Panasonic
39.	R13	4k7	SMD thick film resistor 4k7 0603 1% 100 mW Panasonic
40.	R17	154k	SMD thick film resistor 154k 0805 1% 125 mW Panasonic
41.	R24	270k	SMD thick film resistor 270k 0603 1% 100 mW Panasonic
42.	R25	10k	SMD thick film resistor 10k 0805 1% 125 mW Panasonic
43.	R26	8R2	SMD thick film resistor 8 Ω 1206 1% 500 mW Panasonic
44.	R28	1k	SMD thick film resistor 1k 1206 1% 250 mW Panasonic
45.	R29	100k	SMD Thermistor, 100 k Ω , NTCG-S Series, 0805 [2012 Metric], 200 mW TDK
46.	R30	34k8	SMD thick film resistor 34k8 0603 1% 100 mW Panasonic
47.	R31, R32	0R56	SMD thick film resistor 0.56 Ω 1206 1% 500 mW Panasonic
48.	R33	51k1	SMD thick film resistor 51k1 0603 1% 100 mW Panasonic
49.	R34	44k2	SMD thick film resistor 44k2 0603 1% 100 mW Panasonic
50.	SB1, SB2, SB3, SB4	Plastic spacer M3 M/F 8/5 HEX6	Plastic spacer internal/external M3x8 thread, 5 mm Würth Elektronik
51.	ST1, ST2, ST3, ST4	Plastic spacer M3 F/F 10/40 HEX6	Plastic spacer internal/internal M3x6 thread, 40 mm Würth Elektronik
52.	T1	750319105	Transformer for DC-DC (NCV1362 flyback 250V-900VDC@40W) converter from Würth Elektronik
53.	TP1	ORANGE	PTH testpoint eyelet 3.2mm orange Keystone Electronics
54.	TP2, TP5	RED	PTH testpoint eyelet 3.2mm red Keystone Electronics
55.	TP3	BROWN	PTH testpoint eyelet 3.2mm brown Keystone Electronics
56.	TP4	BLUE	PTH testpoint eyelet 3.2mm blue Keystone Electronics
57.	TP6	BLACK	PTH testpoint eyelet 3.2mm black Keystone Electronics
58.	W1	AOS247 23x20x1	Ceramic insulation washer without hole for TO247 1mm Fischer Elektronik

SECO-HVDCDC1362-40W15V-GEVB

Layout

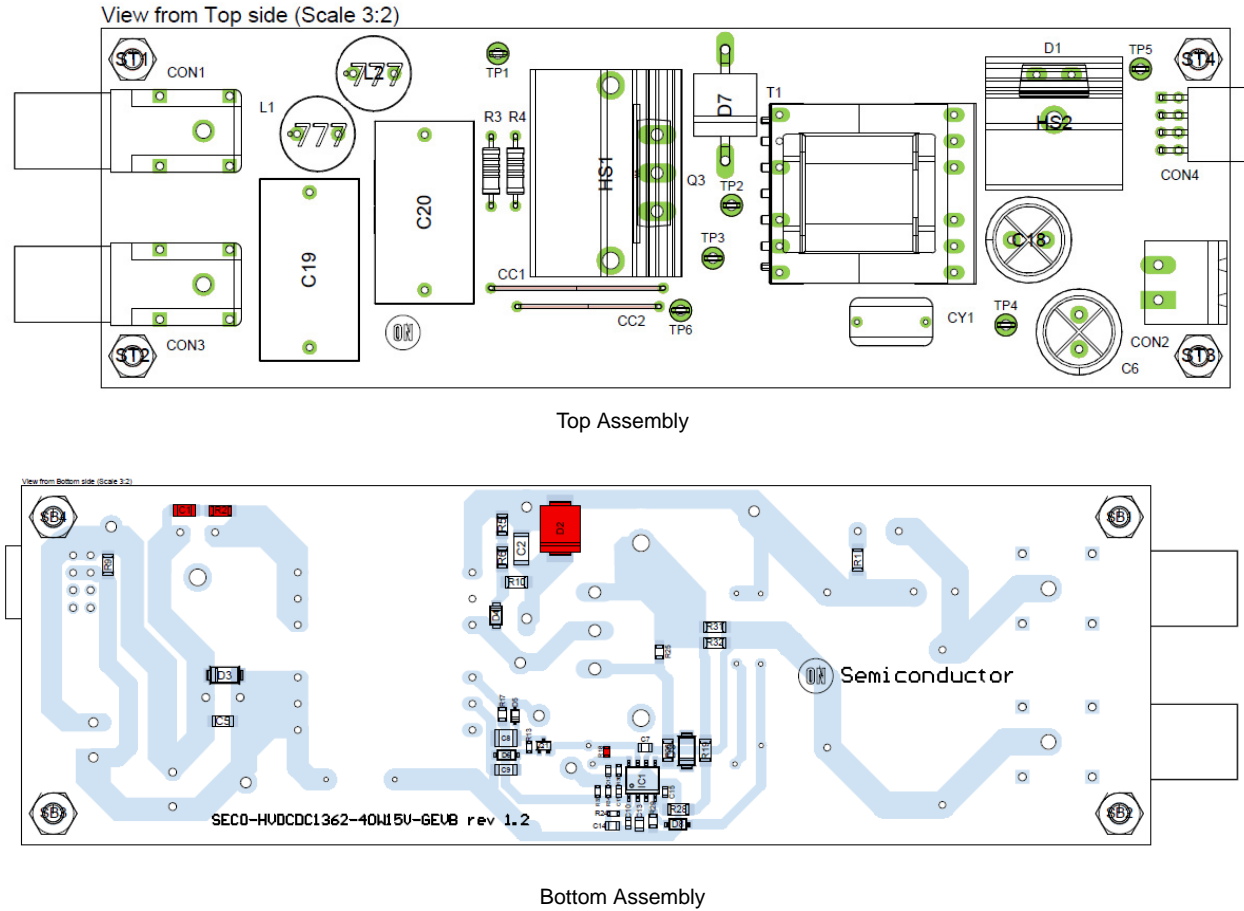


Figure 22. Layout

References

- NCV1362 [Data sheet](#)
- NCV1362 [Application notes](#)
- NCV1362 [Evaluation boards](#)
- NCV1362 [Design worksheet MathCad](#)

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